RC7315

Three-State ATE Pin Electronics Driver

Features

- High output slew rate (1.8 V/ns typical)
- Wide output voltage range (-2.5V to +7V), and up to 9.5 Vp-p swings
- Three-state/high impedance output
- High repetition rate (250 MHz for ECL swings)
- Low output offset (20 mV typical) and output offset drift (0.1 mV/°C typical).
- Low leakage (10 nA typical) and low output capacitance (3 pF typical) in high impedance inhibit mode
- High speed differential inputs with wide common mode range for ease of interface to ECL as well as TTL and CMOS levels
- Output short circuit protection (Safe Operating Area protection with current limiting and thermal shutdown)
- 100 mA typical dynamic current drive capability
- Absolute slew rate control
- Available in 28-pin PLCC
- Packaged parts available in unterminated configurations

Applications

- ATE pin electronics driver
- Precision waveform generator
- Level translator
- Differential line receiver
- General purpose driver
- Laser driver
- CRT preamplifier

Description

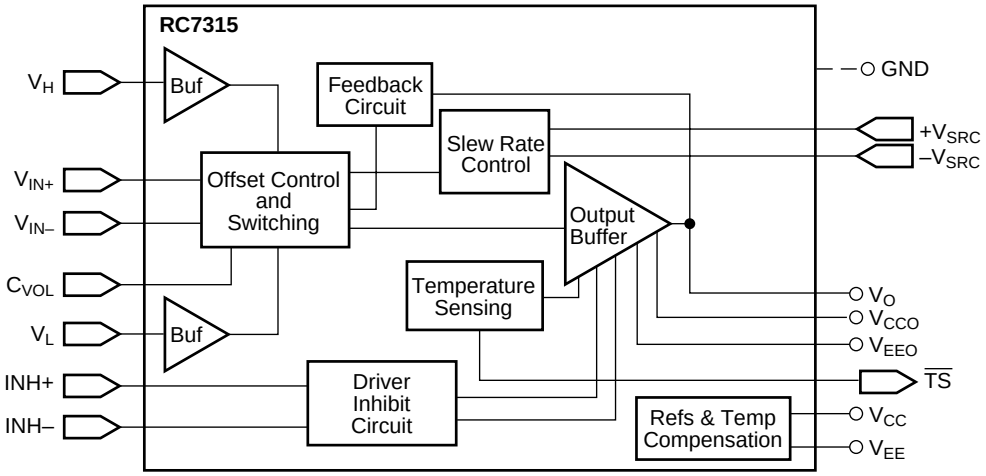
The RC7315 Pin Electronics Driver is designed for use in all high speed ATE systems which require pin drivers with three state capability and high slew rates. The RC7315 has the ability to drive a 50Ω transmission line of up to 2 feet in length with a slew rate of 1.8 V/ns and repetition rate of over 250 MHz for ECL output levels. These features, combined with a maximum output swing of 9.5 Vp-p over the range of -2.5V to +7V, provide this circuit with the ability to test TTL, CMOS, ECL and GaAs devices. The high and low limits of the output swing are set through the program pins V_H and V_L, respectively. The transfer characteristic from the program pins to the output pin is unity gain with very low offset drift. The V_H and V_L inputs have been buffered to operate with low bias currents (1 μA typical) allowing direct coupling to the output of a DAC.

When the RC7315 is used on an I/O pin, it may be forced into the high impedance state through the INH+ and INH- differential inputs. In the high impedance state, excellent isolation is provided between the output of the disabled driver and the pin by virtue of low driver output capacitance (3.0 pF typical) and low output leakage (10 nA typical).

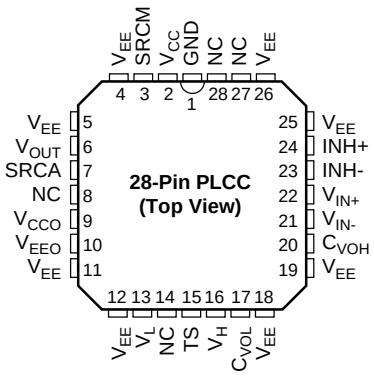
The RC7315 is provided with high speed differential ECL inputs for ease of interface with the differential ECL outputs of a timing generator. The inputs have a voltage range of -2V to +6V, so that if required, an input may be driven by TTL or CMOS devices provided that the other input is fed to the appropriate threshold value.

The RC7315 is implemented using Fairchild Semiconductor's high frequency complementary bipolar process.

Block Diagram



Pin Assignments



Pin Description

Name	Pin Number	Function
C_{VOL}, C_{VOH}	17	**Bypass capacitor for V_{OH} and V_{OL} respectively**. Pins C_{VOL} and C_{VOH} should be bypassed to the ground plane with a 1,000 pF chip capacitor placed as close to the pin as possible.
GND	1	**Chip ground**. Should be connected to the printed circuit board's ground plane at the pin.
INH+ INH-	23, 24	**Differential digital inputs**. When INH is true (i.e. INH+ > INH-) the driver is forced into the high impedance state. Although these inputs are normally driven by ECL signals, they have a wide enough common mode range that any one of the inputs may be driven by a TTL or CMOS signal provided that the other input is tied to the appropriate threshold voltage.
SRCA	7	**Slew rate control for both edges**. Slew rate of both rising and falling edges decreases as the control current is changed from 0 mA to -0.5 mA. SRC can be programmed with a current DAC or set to a fixed value using a resistor.
SRCM	3	Increases the speed of the falling edge to match the rising edge.
$\overline{TS}$	15	**Active low output notifies thermal shutdown has occurred**. In the event of a short circuit or other fault that causes the die temperature to become excessively large, the thermal shutdown will kick in at a die temperature between 115°C and 160°C. If the fault persists, the device will toggle back and forth between shutdown and normal operation at a frequency in the tens of Hertz. $\overline{TS}$ is an open collector output capable of driving two standard TTL loads. The $\overline{TS}$ pins of several drivers may be wire-ORed together and input to a latch to indicate an alarm condition.
V_{CC}	2	**Quiet positive supply**. The nominal value is 10V ±3%. For output high voltage levels (V_{OH}) greater than the nominal value of +7V, V_{CC} should be raised 3V above the maximum value of V_{OH}. Whenever V_{EE} is lowered to provide margin at the output low level, V_{CC} should also be lowered by the same amount. V_{CC} should be bypassed to ground with a 10,000 pF chip capacitor placed as close to the pins as possible.
V_{CCO}	9	**Positive supply for the RC7315 output stage**. This supply is brought out separately to minimize the supply noise generated when the output switches. V_{CCO} should be bypassed to the ground plane with a 10,000 pF chip capacitor placed as close to the pin as possible and then immediately connected to V_{CC}.
V_{EE}	4, 5, 11, 12, 18, 19, 25, 26	**Quiet negative supply**. The nominal value is -5.2V ±5%. For output low voltage levels (V_{OL}) less than the nominal value of -2.2V, V_{EE} should be lowered 3V below the minimum value of V_{OL}. Whenever V_{CC} is raised to provide margin at the output high level, V_{EE} should also be raised by the same amount. V_{EE} should be bypassed to ground with a 10,000 pF chip capacitor placed as close to the pins as possible.

Pin Descriptions (continued)

Name	Pin Number	Function
V_{EEO}	10	**Negative supply for the RC7315 output stage**. This supply is brought out separately to minimize the supply noise generated when the output switches. V_{EEO} should be bypassed to the ground plane with a 10,000 pF chip capacitor placed as close to the pin as possible and then immediately connected to V_{EE}.
V_H	16	Analog program input that sets the output high level (V_{OH}). The transfer characteristic from V_H to V_{OH} is nominally unity gain.
V_{IN+}, V_{IN-}	21, 22	**Differential digital inputs**. The output will toggle between the two levels dictated by V_H and V_L as the differential signal is switched. Although these inputs are normally driven by ECL signals, they have a wide enough common mode range that any one of the inputs may be driven by a TTL or CMOS signal provided that the other input is tied to the appropriate threshold voltage.
V_L	13	Analog program input that sets the output low level (V_{OL}). The transfer characteristic from $V_L$to V_{OL} is nominally unity gain.
V_O		**Driver output on RC7315**. The output impedance is 8Ω ±2Ω. The output is usually back terminated in the characteristic impedance of the transmission line it drives. For a 50Ω line, a 40Ω ±1% resistor should be placed externally as close to the output pin as possible to minimize reflections and ringing. The resistor should also be able to dissipate 0.8Ω to sustain the short circuit current of the output.
NC	8, 14, 27, 28	**No connection**.

Absolute Maximum Ratings[1]

Parameter	Min.	Max.	Units
Positive power supply, V_{CC}		13	V
Negative power supply, V_{EE}	-8.2		V
Difference between V_{CC} and V_{EE}		17	V
Input voltage at V_{IN+}, V_{IN-}, INH+, and INH-	V_{CC}-12	V_{EE}+12	V
Input Voltage at V_H, V_L	V_{CC}-13	V_{EE}+13	V
Differential input voltage, $\lvert V_{IN+} - V_{IN-} \rvert$, $\lvert V_{INH+} - V_{INH-} \rvert$		6	V
Difference between V_H & V_L ($\lvert V_H - V_L \rvert$)		11	V
Input voltage at SRCA	-3	+7	V
Slew rate control current	-2.0		mA
Driver Output Voltage	V_{CC}-13	V_{EE}+13	V
Output voltage at $\overline{TS}$		5	V
Duration of short-circuit to ground		Indefinite	
Operating temperature range	0	70	°C
Storage temperature range	-65	+125	°C
Lead temperature range (Soldering 10 seconds)		300	°C

Notes:

1. “Absolute maximum ratings” are those beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the device should be operated at these limits. If the device is subjected to the limits in the absolute maximum ratings for extended periods, its reliability may be impaired. The tables of Electrical Characteristics provide conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameters	Min.	Typ.	Max.	Units
T_C	Case operating temperature		25		°C
V_{CC}	Positive supply voltage	9.7	10.0	10.3	°C
V_{EE}	Negative supply voltage	-5.45	-5.2	-4.95	V
V_{CC}-V_{EE}	Difference between positive and negative supply		15.2	15.8	V
V_{OH}, V_{OL}	Range for output high level and output low level	-2.0		7.0	V
V_{OH}-V_{OL}	Output amplitude	0.1		10.0	V

DC Electrical Characteristics

V_{CC} = 10V ±3%, V_{EE} = -5.2V ±5%, T_A = 25°C (still air) and the load is a 50Ω transmission line with 2.0 ns one-way delay, unless otherwise specified. The transmission line is back-terminated in 50Ω (±5%) using an external resistor.

Symbol	Parameters	Test Conditions	Min.	Typ.	Max.	Units
Differential Inputs V_{IN+}, V_{IN-}, V_{INH+}, V_{INH-}						
V_{IN+}, V_{IN-}	Absolute Voltage @ Data Inputs		-2.0		+6.0	V
V_{INH+}, V_{INH-}	Absolute Voltage @ Inhibit Inputs INH+, INH-		-2.0		+6.0	V
V_{ID}	Differential Input Range	$\lvert V_{IN+} - V_{IN-} \rvert$	0.4	ECL	5.0	V
V_{DINH}	Differential Inhibit Input Range	$\lvert V_{INH+} - V_{INH} \rvert$	0.4	ECL	5.0	V
I_{IN+}, I_{IN-}	Input Bias Current @ Data Inputs	-2V ≤ V_{IN+}, V_{IN-} ≤ +6V		-100		µA
I_{INH+}, I_{INH-}	Input Bias Current @ Inhibit Inputs	-2V ≤ V_{INH+}, V_{INH-} ≤ +5V		-100		µA
Absolute Slew Rate Control Input SRCA						
V_{SRCA}	Compliance Voltage Range		-2.0		+2.0	V
I_{SRCA}	Control Current Range		-0.5		+0.5	V
Matching Slew Rate Control Input SRCM						
V_{SRCM}	Compliance Voltage Range		-2.0		+2.0	V
I_{SRCM}	Control Current Range		-0.5		+0.5	V
Voltage Program Inputs V_H, V_L						
V_H	V_H Range	V_{CC} = 10V; V_{EE} = -5.2V	-2.0		+7.0	V
		V_{CC} = 12V; V_{EE} = -3.2V	0		+9.0	V
		V_{CC} = 8V; V_{EE} = -7.2V	-4.0		+5.0	V
V_L	V_L Range	V_{CC} = 10V; V_{EE} = -5.2V	-2.5		+6.0	V
		V_{CC} = 12V; V_{EE} = -3.2V	-0.5		+8.0	V
		V_{CC} = 8V; V_{EE} = -7.2V	-4.5		+4.0	V
I_H	Bias Current @ V_H	-1V ≤ V_H ≤ +7V; V_L = -2.0V		-1		µA
I_L	Bias Current @ V_L	-2V ≤ V_L +5V; V_H = 6.0V		-1		µA
TCI_H	Temperature Drift in I_H	V_H = 7.0V; 25°C ≤ T_C ≤ 70°C output not switching			0.1	µA/°C
TCI_L	Temperature Drift in I_L	V_L= -2.0V; 25°C ≤ T_C ≤ 70°C output not switching			0.1	µA/°C
$V_{H,L}BW$	-3 dB bandwidth from V_H or V_L to the output	-1V ≤ V_H ≤ +7V; -2V ≤ V_L ≤ +6V; V_H-V_L= 2.0V		50		kHz

DC Electrical Characteristics (continued)

Symbol	Parameters	Test Conditions	Min.	Typ.	Max.	Units
Signal Output V_O, V_{OTERM}						
V_O	Output Voltage Range	V_{CC} = 10V; V_{EE} = -5.2V	-2.5		+7.0	V
		V_{CC} = 12V; V_{EE} = -3.2V	-0.5		+9.0	V
		V_{CC} = 8V; V_{EE} = -7.2V	-4.5		+5.0	V
V_A	Amplitude	$\lvert V_{OH} - V_{OL} \rvert$	0.3		9.5	V
δV_{OH}	Offset to Output High Level	V_H = 0, no load; V_L = -2V		±30		mV
		$\delta V_{OH} = \lvert V_H - V_{OH} \rvert$				
δV_{OL}	Offset to Output Low Level	V_H = 0, no load; V_H = +7V		±30		mV
		$\delta V_{OL} = \lvert V_L - V_{OL} \rvert$				
VTC	Output Voltage Drift	-1V ≤ V_{OH} ≤ +7V;		0.1		mV/°C
		-2V ≤ V_{OL} ≤ +6V;		0.1		
ε_G	Gain Error	-1V ≤ V_{OH} ≤ +7V;		1	2	$\%V_{SET}$
		-2V ≤ V_{OL} ≤ +6V		1		
ε_L	Linearity Error	-2V ≤ V_{OUTPUT} ≤ +7		0.7		$\%V_{SET}$
Z_{OUT}	Output Impedance I_{OUT} 50 mA	V_O		8		Ω
I_{ZL}	Output Leakage Current in Inhibit Mode	-2.0V ≤ V_O ≤ +7V		0.5	2	µA
I_{DC}	DC Current Drive		50			mA
I_{AC}	AC Current Drive		70	100		mA
Thermal Shutdown Output (TS)						
I_{CL}	Short Circuit Current Limit				145	mA
VTS	TS Flag Output Level	I_{OL} = 4 mA			0.5	V
T_{TS}	Shutdown Die Temperature			145		°C
Other						
$V_{S\ MAX}$	Maximum Rail to Rail Supply Voltage	V_{CC} - V_{EE}			16	V
V_{CC}	Positive Supply		+8.0	+10.0	+12.0	V
V_{EE}	Negative Supply		-7.2	-5.2	-3.2	V
I_{CC}	Positive Supply Current			85		mA
IEE	Negative Supply Current			90		mA
$PSRV_O$	Output Level Power Supply	V_{CC}; ΔV_{CC} = ±2.5%	40			dB
	Rejection Ratio	V_{EE}; ΔV_{EE} = ±2.5%	40			dB
$PSRV_{SL}$	Output Slew Rate Power Supply	V_H = 5V				
	Rejection Ratio @ V_{CC}	and ΔV_{CC} = ±200 mV		4		
	@ V_{EE}	V_L = 0V ΔV_{EE} = ±200 mV		4		%
T_A	Operating Temperature Range	Still Air	0	25	40	°C
		Air Flow > 300 l_{fpm}	0	25	70	°C

AC Electrical Characteristics

V_{CC} = 10V ±3%, V_{EE} = -5.2V ±5%, T_A = 25°C (still air) and the load is a 50Ω transmission line with 2.0 ns one-way delay, unless otherwise specified. The transmission line is back-terminated in 50Ω (±5%) using an external resistor. The measurement probe is a high impedance FET probe with capacitance no greater than 3 pF and resistance no smaller than 10 kΩ.

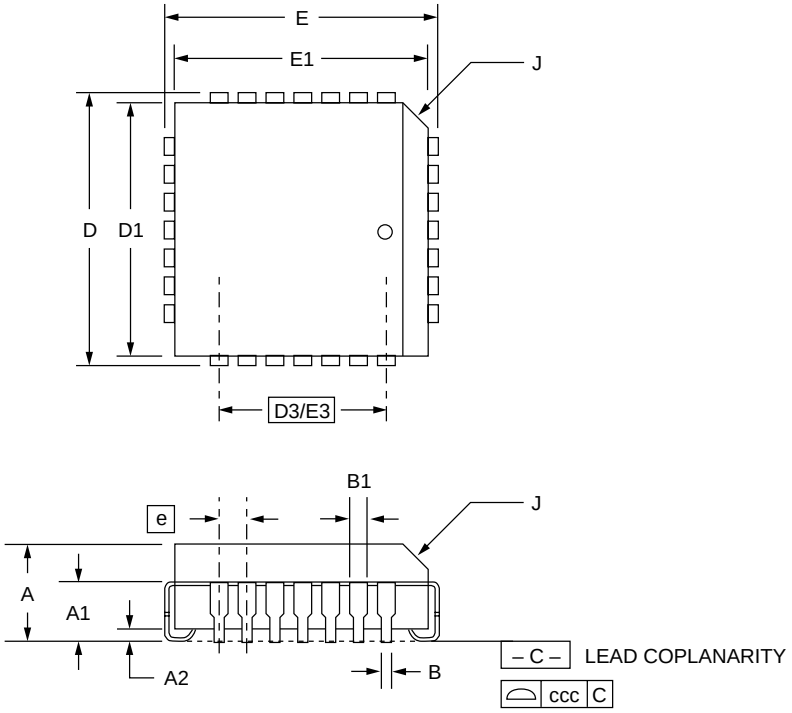
Symbol	Parameters	Test Conditions	Min.	Typ.	Max.	Units
SLR	Slew Rate (Slew rate not adjusted)	V_H - V_L = 5V; Measured between 20% and 80% points.				
		With probe only as load	1.3	1.8		V/ns
		With probe and transmission line	1.2	1.7		V/ns
t_R,	Rise Time, and	Load is Probe Only;				
t_F	Fall Time	V_A = 1V (20% to 80%)		0.6		ns
	(Slew rate not adjusted)	V_A = 3V (10% to 90%)		1.6		ns
		V_A = 5V (10% to 90%)		2.5		ns
f	Toggle Rate	Amplitude = 0.8 Vp-p	250			MHz
		Amplitude = 5.0 Vp-p	125			MHz
t_{PLH}	Low to High Propagation Delay	f = 10 MHz; V_{OH} = +0.4V;				
		V_{OL} = -0.4V		1.6		ns
t_{PHL}	High to Low Propagation Delay	f = 10 MHz; V_{OH} = +0.4V;				
		V_{OL} = -0.4V		1.4		ns
Δt_P	Propagation Delay Match	$\lvert t_{PLH} - t_{PHL} \rvert$		200		ps
t_PTC	Propagation Delay Temperature Coefficient			2		ps/°C
tPW_{min}	Minimum Pulse Width	V_H - V_L - 2.0V; pulsewidth at which amplitude drops by 50 mV, measured between 50% points.		2.0		ns
Δt_PPW	Propagation Delay Variation with Pulse Width	2 ns < PW < 98 ns; f = 10 MHz; V_{OH} = +0.4V; V_{OL} = -0.4V		±75		ps
t_{PS}	Preshoot	0.5V < V_A < 5.0V			15mV + 3% of V_A	
t_{OS}	Overshoot	0.5V < V_A < 5.0V			50mV + 4% of V_A	
t_S	Output Settling Time	V_A < 5V;				
		To within 3% of V_A		8		ns
		To within 1% of V_A		10		ns
t_{PHZ}	Propagation Delay from Logic High to Inhibit Mode	V_{OH} = 1V; V_{OL} = -1V Load = 100Ω // 15pF		2.9		ns
t_{PLZ}	Propagation Delay from Logic Low to Inhibit Mode	Propagation delay is measured to the point at which voltage has changed by 200 mV.		2.9		ns
t_{PZH}	Propagation Delay from Inhibit Mode from Logic High			2.9		ns
t_{PZL}	Propagation Delay from Inhibit Mode to Logic Low			2.9		ns
C_Z	Output capacitance in Inhibit Mode			3		pF

Mechanical Dimensions — 28-pin PLCC

Symbol	Inches		Millimeters		Notes
	Min.	Max.	Min.	Max.	
A	.165	.180	4.19	4.57	
A1	.090	.120	2.29	3.05	
A2	.020	—	.51	—	
B	.013	.021	.33	.53	
B1	.026	.032	.66	.81	
D/E	.485	.495	12.32	12.57	
D1/E1	.450	.456	11.43	11.58	3
D3/E3	.300 BSC		7.62 BSC		
e	.050 BSC		1.27 BSC		
J	.042	.048	1.07	1.22	2
ND/NE	7		7		
N	28		28		
ccc	—	.004	—	0.10	

Notes:

1. All dimensions and tolerances conform to ANSI Y14.5M-1982
2. Corner and edge chamfer (J) = 45°
3. Dimension D1 and E1 do not include mold protrusion. Allowable protrusion is .101" (.25mm)



Ordering Information

Part Number	Package	Operating Temperature Range
RC7315QF	28-pin PLCC	0°C to +70°C